

Schottky Barrier Diode

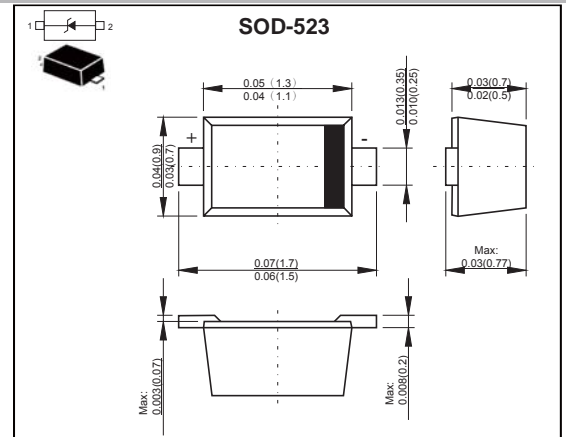
VOLTAGE RANGE: 40V PEAK PULSE POWER:150mW

FEATURES

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability

MECHANICAL DATA

- Case: SOD-523 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Mounting Position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

Parameter	Symbol	Limit	Unit
Peak reverse voltage	VRM	40	V
DC reverse voltage	VR	30	V
Mean rectifying current	IO	30	mA
Non-repetitive Peak Forward Surge Current@t=8.3ms	IFSM	200	mA
Power dissipation	PD	150	mW
Thermal Resistance Junction to Ambient	RθJA	667	°C/W
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55~+150	°C

Electrical Specification (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	VF			0.37	V	IF=1mA
Reverse current	IR			0.5	μA	VR=30V
Capacitance between terminals	CT		2		pF	VR=1V, f=1MHZ

MARKING: 5

RATINGS AND CHARACTERISTIC CURVES

Typical Characteristics

